

Data sheet acquired from Harris Semiconductor SCHS020C – Revised October 2003

CMOS Hex Buffers/Converters

High-Voltage Types (20-Volt Rating)

Inverting Type: CD4009UB Non-Inverting Type: CD4010B

■ CD4009UB and CD4010B Hex Buffer/Converters may be used as CMOS to TTL or DTL logic-level converters or CMOS high-sink-current drivers.

The CD4049UB and CD4050B are preferred hex buffer replacements for the CD4009UB and CD4010B, respectively, in all applications except multiplexers. For applications not requiring high sink current or voltage conversion, the CD4069UB Hex Inverter is recommended.

The CD4009UB and CD4010B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, MT, and NSR suffixes), and 16-lead thin shink small-outline packages (PW and PWR suffixes).

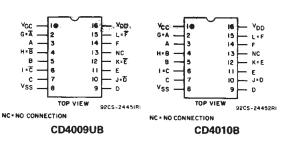
CD4009UB, CD4010B Types

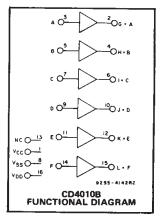
Features:

- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- 5-V, 10-V, and 15-V parametric ratings

Applications:

- CMOS to DTL/TTL hex converter
- CMOS current "sink" or "source" driver
- CMOS high-to-low logic-level converter
- Multiplexer 1 to 6 or 6 to 1





TERMINAL ASSIGNMENTS

MAXIMUM RATINGS, Absolute-Maximum Values:
DC SUPPLY-VOLTAGE RANGE, (VDD)
Voltages referenced to V _{SS} Terminal)0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS0.5V to V _{DD} +0.5V
DC INPUT CURRENT, ANY ONE INPUT
POWER DISSIPATION PER PACKAGE (PD):
For T _A = -55°C to +100°C
For T _A = +100°C to +125°C Derate Linearity at 12mW/°C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)
OPERATING-TEMPERATURE RANGE (T _A)55°C to +125°C
STORAGE TEMPERATURE RANGE (T _{stg})65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):
At distance 1/16 \pm 1/32 inch (1.59 \pm 0.79mm) from case for 10s max +265°C

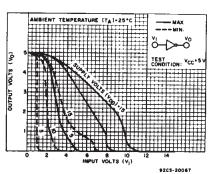


Fig. 3 — Minimum and maximum voltage transfer characteristics—CD4009UB.

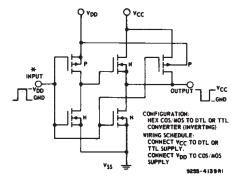


Fig. 1 — Schematic diagram of CD4009UB— 1 of 6 identical stages.

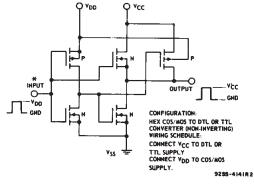
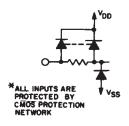


Fig. 2 — Schematic diagram of CD40108— 1 of 6 identical stages.



CD4009UB, CD4010B Types

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	Li		
CHARACTERISTIC	MIN.	MAX.	UNITS
Supply-Voltage Range (For TA = Full		1	
Package Temperature Range), VDD	3	18	V
Vcc*	3	V _{DD}	1
Input Voltage Range (V _I)	Vcc*	V _{DD}	V

^{*}The CD4009UB and CD4010B have high-to-low level voltage conversion capability but not low-to-high level, therefore it is recommended that $V_{DD} > V_I > V_{CC}$.

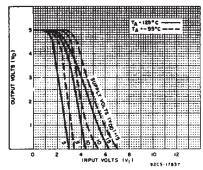


Fig. 4 — Typical voltage transfer characteristics as function of temp.—CD4009UB.

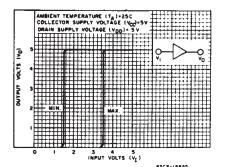


Fig. 5 – Minimum and maximum voltage transfer characteristics (V_{DD}=5)-CD4010B.

STATIC ELECTRICAL CHARACTERISTICS

CHARAC- TERISTIC	CONDITIONS LIMITS AT INDICATED TEMPERATURES (°C)					UNITS					
	Vo	VIN	V_{DD}	-55	-40	+85	+125		+25		
	(V)	(V)	(V)					Min.	Тур.	Max.	
Quiescent		0,5	5	_1	1	30	30		0.02	1	
Device		0,10	10	2	2	60	60	_	0.02	2	
Current, I _{DD}		0,15	15	4	4	120	120		0.02	4	μΑ
Max.	_	0,20	20	20	20	600	600		0.04	20	
Output Low	0.4	0,5	4.5	3.2	3.1	2.1	1.8	2.6	3.4		
(Sink)	0.4	0,5	5	3.75	3.6	2.4	2.1	3	4		
Current	0.5	0,10	10	10	9.6	6.4	5.6	8	10	_	
IOL Min.	1.5	0,15	15	30	40	19	16	24	36	-	mA
Output High	4.6	0,5	5	-0.25	-0.23	-0.18	-0.15	0.2	-0.4	_	1004
(Source)	2.5	0,5	5	-1	-0.9	-0.65	-0.58	-0.8	-1.6		
Current	9.5	0,10	10	-0.55	-0.5	-0.38	-0.33	-0.45	-0.9	_	
I _{OH} Min.	13.5	0,15	15	-1.65	-1.6	-1.25	-1.1	-1.5	-3	- 1	
Output Voltage:	_	0,5	5		0.	05		_	0	0.05	
Low-Level,	_	0,10	10		0.	05			0	0.05	
VOL Max.	-	0,15	15		0.	05		_	0	0.05	
Output Voltage:		0,5	5		4.	95		4.95	5	_	٧
High-Level,	_	0,10	10		9.	95		9.95	10		
V _{OH} Min.		0,15	15		14	.95		14.95	15		
Input Low	4.5	_]	5			1			_	1	
Voltage:	9	_	10			2			_	2	
V _{IL} Max. CD4009UB	13.5	_	15		2	.5		_	-	2.5	
Input Low Voltage:	0.5	_	5			1.5		_		1.5	
VII Max.	1		10			3			1	3	
CD4010B	1.5		15			4		-	-	4	
Input High	0.5	_	5			4		4	_	_	V
Voltage:	1 1		10	8			8		-		
V _{IH} Min. CD4009UB	1.5	-	15		1:	2.5		12.5		-	
Input High Voltage:	4.5	<u> </u>	5		:	3.5		3.5	_	_	
V _{1H} Min.	9		10			7		. 7	_		
CD4010B	13.5		15		1	11		11	-		
Input Current, I _[N] Max.		0,18	18	±0.1	±0.1	±1	±1	-	±10 ⁻⁵	±0.1	μΑ

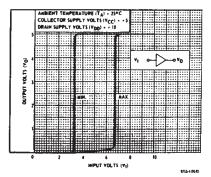


Fig. 6 – Minimum and maximum voltage transfer characteristics (V_{DD} =10)—CD4010B.

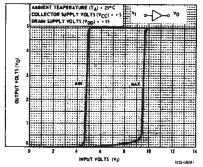


Fig. 7 — Minimum and maximum voltage transfer characteristics (V_{DD}=15)—CD4010B.

CD4009UB, CD4010B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A =25°C; Input t_r , t_f =20 ns, C_L =50 pF, R_L =200 $K\Omega$

	C	ONDITION	s	LIN		
CHARACTERISTIC	V _{DD} (V)	V _I (V)	Vcc (V)	TYP.	MAX.	UNIT
Propagation Delay Time: Low-to-High, tPLH	5	5	5	70	140	
cow-to-riight, tPEH	10	10	10	40	80	1
CD4009UB	10	10	5	35	70	ns
0010000	15	15	15	30	60	""
	15	15	5	30	60	-
	5	5	5	100	200	
	10	10	10	50	100	1
CD4010B	10	10	5	50	100	ns
0040100	15	15	15	35	70	113
	15	15	5	35	70	
High-to-Low, tPHL	5	5	5	30	60	
mgn to Low, tPHL	10	10	10	20	40	
CD4009UB	10	10	5	15	30	ns
	15	15	15	15	30	115
	15	15	5	10	20	
-	5	5	5	65	130	
	10	10	10	35	70	
CD4010B	10	10	5	30	70	ns
0040100	15	15	15	25	50	115
	15	15	5	20	40	
Transition Time:		-	 		100	
Low-to-High, tTLH	5	5	5	150	350	
	10	10	10	75	150	ns
	15	15	15	55	110	
High-to-Low, tTHL	5	5	5	35	70	
	10	10	10	20	40	ns
	15	15	15	15	30	
Input Capucitance, C _{IN} CD4009UB	_	_	_	15	22.5	
CD4010B	_	_	_	5	7.5	ρF

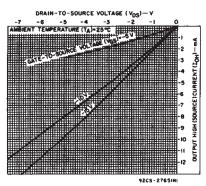


Fig. 11 — Typical output high (source) current characteristics,

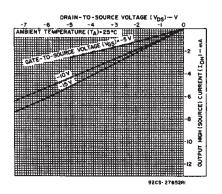


Fig. 12 — Minimum output high (source) current characteristics.

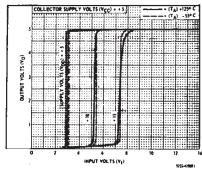


Fig. 8 — Typical voltage transfer characteristics as a function of temperature—CD4010B.

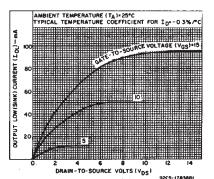


Fig. 9 — Typical output low (sink) current characteristics.

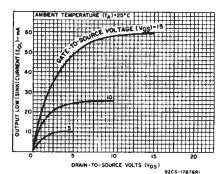


Fig. 10 — Minimum output low (sink) current characteristics.

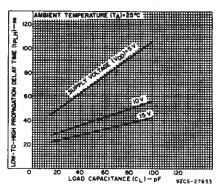


Fig. 13 — Typical low-to-high propagation delay time vs. load capacitance (CD4009UB).

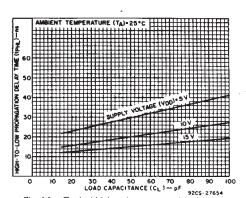


Fig. 14 — Typical high-to-low propagation delay time vs. load capacitance (CD4009UB).

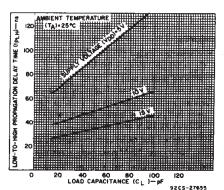


Fig. 15 — Typical low-to-high propagation delay time vs. load capacitance (CD4010B).

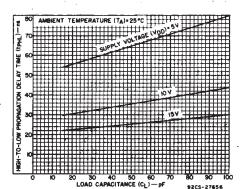


Fig. 16 — Typical high-to-low propagation delay time vs. load capacitance (CD40108).

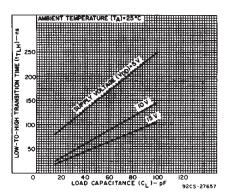


Fig. 17 — Typical low-to-high transition time vs. load capacitance.

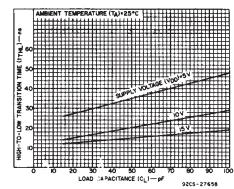


Fig. 18 — Typical high-to-low transition time vs. load capacitance.

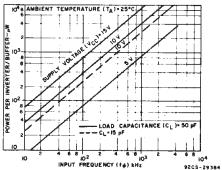


Fig. 19 — Typical dissipation characteristics.

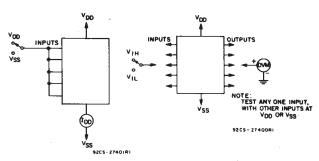
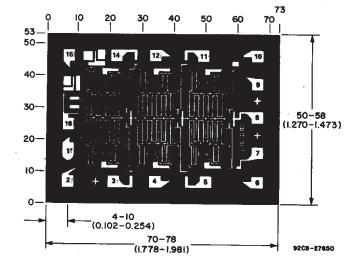


Fig. 20 — Quiescent device current test circuit,

Fig. 21 — Noise immunity test circuit.



NOTE:

MEASURE INPUTS
SEQUENTIALLY,
TO BOTH YOD AND VSS
CONNECT ALL UNUSED
RIPUTS TO EITHER

VOO OR VSS:

Fig. 22 - Input current test circuit.

Dimensions in parentheses are in millimeters and are derived from the besic inch dimensions as indicated, Grid Graduations Are In Mils (10^{-3} Inch)

Photograph of chip for CD4009UB. Dimensions and pad layout for CD4010B are identical.



PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
89264UKB3T	OBSOLETE	CFP	WR	16		TBD	Call TI	Call TI
CD4009UBE	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD4009UBEE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD4009UBF	ACTIVE	CDIP	J	16	1	TBD	Call TI	Level-NC-NC-NC
CD4009UBF3A	ACTIVE	CDIP	J	16	1	TBD	Call TI	Level-NC-NC-NC
CD4009UBM	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4009UBM96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4009UBM96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4009UBME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4009UBMT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4009UBMTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4009UBNSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4009UBNSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4009UBPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4009UBPWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4009UBPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4009UBPWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4010BE	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD4010BEE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD4010BF	ACTIVE	CDIP	J	16	1	TBD	Call TI	Level-NC-NC-NC
CD4010BF3A	ACTIVE	CDIP	J	16	1	TBD	Call TI	Level-NC-NC-NC
CD4010BM	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4010BM96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4010BM96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4010BME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4010BMT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4010BMTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM



PACKAGE OPTION ADDENDUM

26-Sep-2005

Orderable Device	Status (1)	Package	Package	Pins	Package	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp (3)
		Type	Drawing		Qty			
CD4010BNSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4010BNSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4010BPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4010BPWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4010BPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4010BPWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN

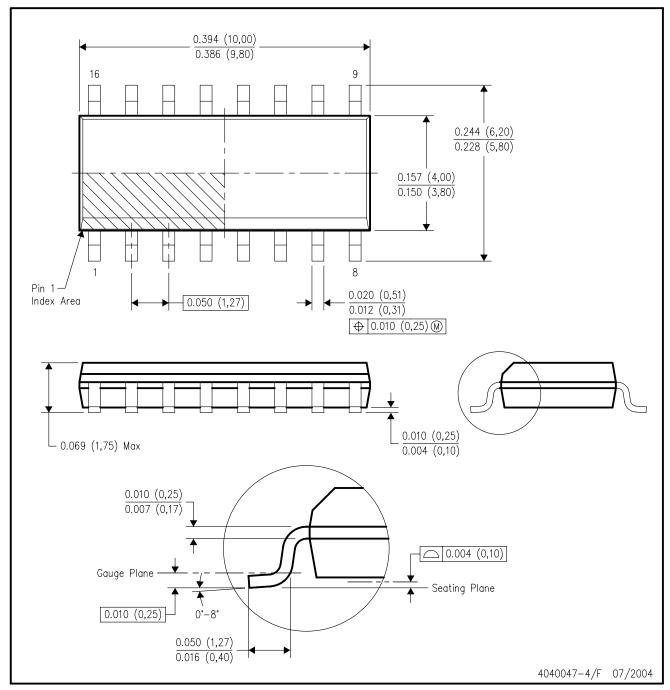


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AC.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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